

3.0-8.0GHz, 10W, 28V GaN Fully matched PA Module

Description

The GMAH3080-10C9 is a 10-watt ,single stage integrated Power Amplifier Module, designed for broad band applications, with frequencies from 3 to 8GHz. The module is 50 Ω input/output matched and requires minimal external components. It can work at higher voltage like 32V with increased power capability. This module can support CW and pulsed CW, and any other format modulation signal.

• Innogration

Within extended band from 2 to 8GHz, it can still deliver more than 6W.

The module implements wideband power amplifier in form of multi chips, housed in cost effective plastic open cavity package, offers a much lower cost than traditional MMIC solutions.

	V	ds= 28V, Vgs=-2.3	37V,Idq=25mA		
	Pulse CW, 50us, 20%				
Freq(MHz)	P-1(dBm)	P-1Gain(dB)	P-3(dBm)	P-3(W)	Eff (%)
3000	39.41	12.1	40.56	11.4	50.4
3200	39.63	12.4	40.79	12.0	55.6
3400	40.14	12.1	41.00	12.6	58.2
3600	40.30	12.5	41.00	12.6	56.0
3800	40.09	12.1	40.96	12.5	48.1
4000	39.59	11.7	40.72	11.8	39.7
4200	38.80	11.8	40.25	10.6	39.4
4400	38.68	12.2	40.36	10.9	36.0
4600	38.71	12.1	40.67	11.7	36.2
4800	38.46	12.5	40.57	11.4	37.4
5000	38.72	13.6	41.03	12.7	41.7
5200	39.35	13.8	41.28	13.4	45.4
5400	39.71	13.4	41.54	14.3	50.7
5600	39.94	13.6	41.54	14.3	54.1
5800	40.05	11.9	41.45	14.0	56.2
6000	40.23	11.3	41.36	13.7	55.4
6200	40.06	11.4	41.51	14.2	56.6
6400	40.27	10.5	41.43	13.9	53.6
6600	39.88	9.5	41.09	12.9	48.3
6800	39.78	9.4	40.89	12.3	44.4
7000	39.42	9.5	40.60	11.5	38.5
7200	39.51	9.7	40.80	12.0	39.0
7400	39.61	10.8	40.86	12.2	39.3
7600	39.56	11.3	40.78	12.0	38.1
7800	39.58	10.9	40.93	12.4	43.7
8000	39.09	9.6	40.37	10.8	41.2

Innogration (Suzhou) Co., Ltd.

Document Number: GMAH3080-10C9 Preliminary Datasheet V1.0

Product Features

• Operating Frequency Range: 3-8GHz

• Operating Drain Voltage: +28 V (Up to 32V)

• 50 Ω Input/Output

• Psat≥40 dBm

• Power gain:>9dB

• Minimum efficiency:>35%

• 12x10 mm Surface Mount Package

• Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

Applications

• • Ultra Broadband Amplifiers

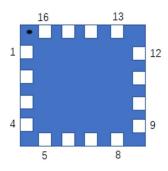
• • Fiber Drivers

• • Test Instrumentation

• • EMC Amplifier Drivers

• • 2-way Radios

Pin Configuration and Description (Top view)



Pin No.	Symbol	Description
4	RF IN	RF Input
9	RF OUT	RF Output
6	Vgs	Gate bias
7	Vdd	Drain bias
Others	NC	No connection
		DC/RF Ground. Proposed to be soldered to heatsink plane directly for the best CW thermal
Package Base	GND	and RF performance. Soldered through high density vias or copper coin also allowed ,but
		will result in excessive junction temperatures and different RF performance

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit		
DrainSource Voltage	V _{DSS}	150	Vdc		
GateSource Voltage	V _{GS}	-10 to +2	Vdc		
Operating Voltage	V _{DD}	+36	Vdc		
Storage Temperature Range	Tstg	-65 to +150	°C		
Case Operating Temperature	Tc	+150	°C		
Operating Junction Temperature	T _J	+225	°C		



Innogration (Suzhou) Co., Ltd.

Document Number: GMAH3080-10C9 Preliminary Datasheet V1.0

Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	Date	G	00/14/
T _C = 85°C, DC test	Rejc	0	°C/W

Table 3. Electrical Characteristics

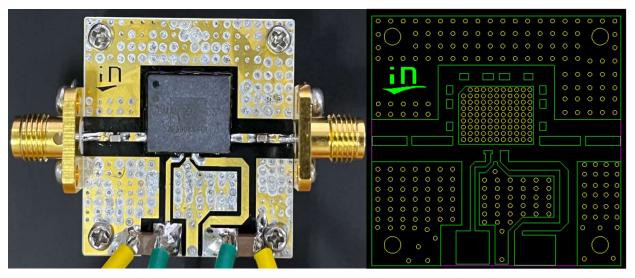
Parameter	Condition	Min	Тур	Max	Unit
Frequency Range		3000		8000	MHz
Power Gain @ Psat		9			dB
P _{SAT}	Pulse	39	40		dBm
Drain Efficiency @ P _{SAT}		35			%
Unless otherwise noted: TA = 25°C, Vpp =28 V, Pulse Width=50 us, Duty cycle=20%					

Load Mismatch of per Section (On Test Fixture, 50 ohm system): $V_{DD} = 28 \text{ V}$, $I_{DQ} = 25 \text{ mA}$, f = 6 GHz

VSWR 10:1 at Psat pulse CW Output Power	No Device Degradation
---	-----------------------

Reference Circuit of Test Fixture Assembly Diagram

Figure 1. Test Circuit Component Layout





TYPICAL CHARACTERISTICS

Figure 2. Network analyzer output S11/S21 (Pin=0dBm)

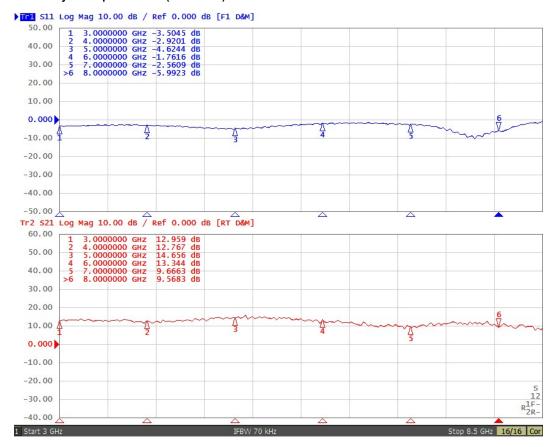
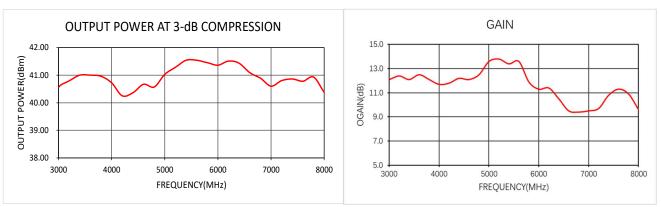


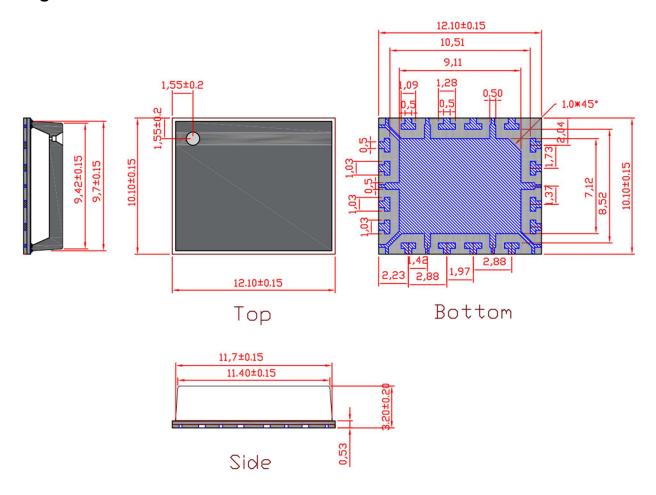
Figure 3. P3dB and Power Gain across the band at 28V





Document Number: GMAH3080-10C9 Preliminary Datasheet V1.0

Package Dimensions (Unit:mm)



Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status
2024/1/19	Rev 1.0	Preliminary Datasheet

Application data based on HJ-24-01

Disclaimers

Specifications are subject to change without notice. Innogration believes the information contained within this data sheet to be accurate and reliable. However, no responsibility is assumed by Innogration for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Innogration . Innogration makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose. "Typical" parameters are the average values expected by Innogration in large quantities and are provided for information purposes only. These values can and do vary in different applications and actual performance can vary over time. All operating parameters should be validated by customer's technical experts for each application. Innogration products are not designed, intended or authorized for use as components in applications intended for surgical implant into the body or to support or sustain life, in applications in which the failure of the Innogration product could result in personal injury or death or in applications for planning, construction, maintenance or direct operation of a nuclear facility. For any concerns or questions related to terms or conditions, pls check with Innogration and authorized distributors Copyright © by Innogration (Suzhou) Co.,Ltd.